

DESCRIPTION

The GLF1110 is an ultra-efficiency, 2 A rated, Load Switch with integrated slew rate control. The best in class efficiency makes it an ideal choice for use in IoT, mobile, and wearable electronics.

The GLF1110 features ultra-efficient I_QSmart™ technology that supports the lowest quiescent current (I_Q) and shutdown current (I_{SD}) in the industry. Low I_Q and I_{SD} solutions help designers to reduce parasitic leakage current, improve system efficiency, and increase battery lifetime.

The integrated slew rate control can also enhance system reliability by mitigating bus voltage swings during switching events. Where uncontrolled switches can generate high inrush currents that result in voltage droop and/or bus reset events, the GLF slew rate control specifically limits inrush currents during turn-on to minimize voltage droop.

The GLF1110 supports an industry leading wide input voltage range and helps to improve operating life and system robustness. Furthermore, one device can be used in multiple voltage rail applications which helps to simplify inventory management and reduce operating cost.

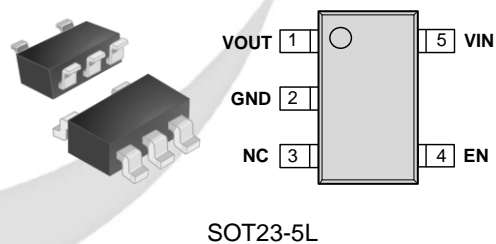
FEATURES

- Wide Input Range: 1.5 V to 5.5 V
6 V abs max
- R_{ON} : 54 mΩ Typ @ 5.5 V_{IN}
- I_{OUT} Max: 2 A
- Ultra-Low I_Q: 2 nA Typ @ 5.5 V_{IN}
- Ultra-Low I_{SD}: 13 nA Typ @ 5.5 V_{IN}
- Controlled Rise Time: 600 μs at 3.3 V_{IN}
- Internal EN Pull-Down Resistor
- Wide Operating Temperature Range:
-40 °C ~ 85 °C
- HBM: 4 kV, CDM: 2 kV

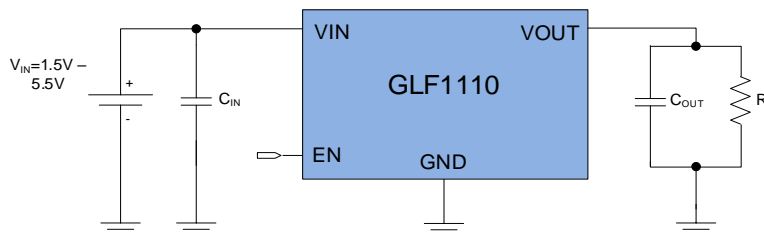
APPLICATIONS

- Telecommunication Module
- Low Power Subsystem
- Mobile Devices

PACKAGE



APPLICATION DIAGRAM



FUNCTIONAL BLOCK DIAGRAM

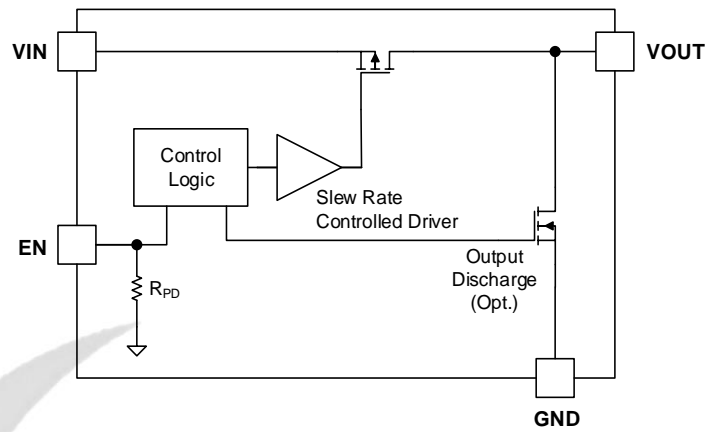
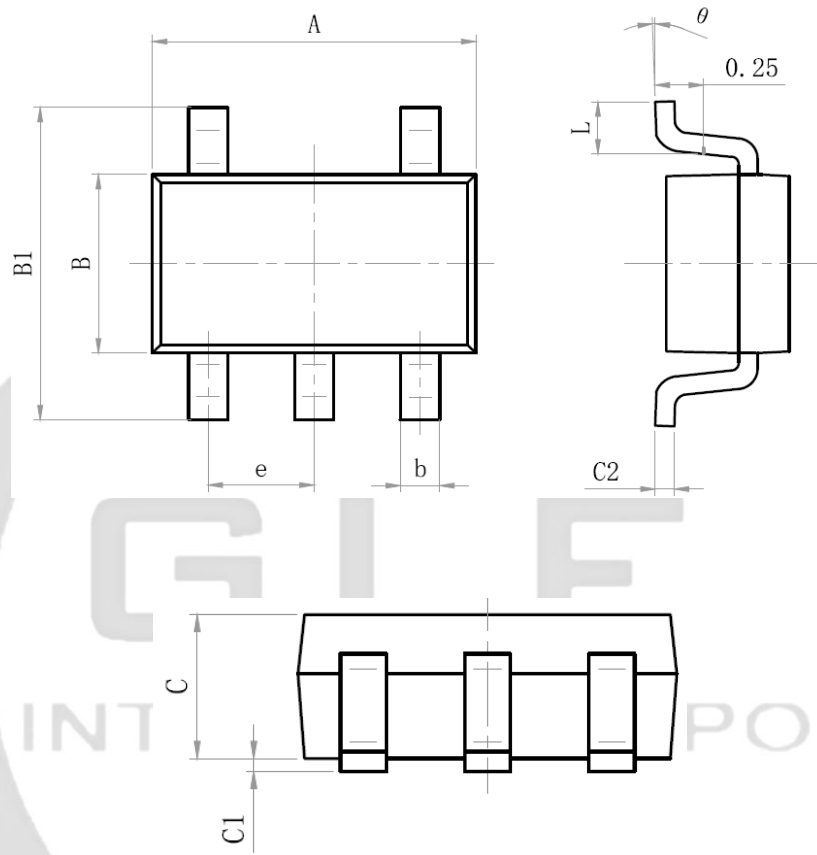


Figure 1. Functional Block Diagram

GLF
INTEGRATED POWER

PACKAGE OUTLINE



Size Mark	Min (mm)	Max (mm)	Size Mark	Min (mm)	Max (mm)
A	2.82	3.02	C	1.05	1.15
e	0.95 (BSC)		C1	0.03	0.15
b	0.28	0.45	C2	0.12	0.23
B	1.50	1.70	L	0.35	0.55
B1	2.60	3.00	theta	0°	8°